TENT AND TRADEMARK OFFICE IN THE UNITED STATE

Applicant:

Goldberg, et a

Serial No.:

09/085,298

Filing Date:

5/27/98

Art Unit:

2823

Examiner:

Eaton, K.

Docket No.: TI-25588

Title:

OF

METHOD FOR THERMAL NITRIDATION AND/OR OXIDATION SEMICONDUCTOR

SURFACE

AND

RELATED

PROCESSING

EQUIPMENT

Amendment under 37 CFR 1.115

Assistant Commissioner of Patents Washington, DC 20231 February 16, 2000

Dear Sir:

MAILING CERTIFICATE UNDER 37 C.F.R. §1.8(A)

I hereby certify that this correspondence is being deposited with the U.S. Postal Service as First Class Mail in an envelope addressed to: Assistant Commissioner for Patents, Washington, D.C. 20231 on

The following amendments and remarks are offered in response to the Examiner's Office Action dated 11/17/99. They are respectfully submitted as a full and complete response to that Action.

Please amend the above-referenced application as follows:

In the Claims:

Please amend the claims as follows:

4. (amended) The method of claim 1, wherein said silicon-containing structure is a silicon substrate and said nitrided portion of said silicon-containing structure is a gate dielectric.